

FEATURES

Multiple pins/software programmable input ranges:

5 V, 10 V, ± 5 V, ± 10 V

Pins or serial SPI®-compatible input ranges/mode selection

Throughput: 250 kSPS

16-bit resolution with no missing codes

INL: ± 0.75 LSB typ, ± 1.5 LSB max (± 23 ppm of FSR)

SNR: 94 dB @ 2 kHz

iCMOS® process technology

5 V internal reference: typical drift 3 ppm/°C;

On-chip temperature sensor

No pipeline delay (SAR architecture)

Parallel (16- or 8-bit bus) and serial 5 V/3.3 V interface

SPI-/QSPI™-/MICROWIRE™-/DSP-compatible

Power dissipation

90 mW @ 250 kSPS

10 mW @ 1 kSPS

48-lead LQFP and LFCSP (7 mm × 7 mm) packages

APPLICATIONS

Process control

Medical instruments

High speed data acquisition

Digital signal processing

Instrumentation

Spectrum analysis

ATE

GENERAL DESCRIPTION

The AD7610 is a 16-bit charge redistribution successive approximation register (SAR), architecture analog-to-digital converter (ADC) fabricated on Analog Devices, Inc.'s iCMOS high voltage process. The device is configured through hardware or via a dedicated write only serial configuration port for input range and operating mode. The AD7610 contains a high speed 16-bit sampling ADC, an internal conversion clock, an internal reference (and buffer), error correction circuits, and both serial and parallel system interface ports. A falling edge on CNVST samples the analog input on IN+ with respect to a ground sense, IN-. The AD7610 features four different analog input ranges: 0 V to 5 V, 0 V to 10 V, ± 5 V, and ± 10 V. Power consumption is scaled linearly with throughput. The device is available in Pb-free 48-lead, low-profile quad flat package (LQFP) and a lead frame chip-scale (LFCSP_VQ) package. Operation is specified from -40°C to $+85^{\circ}\text{C}$.

FUNCTIONAL BLOCK DIAGRAM

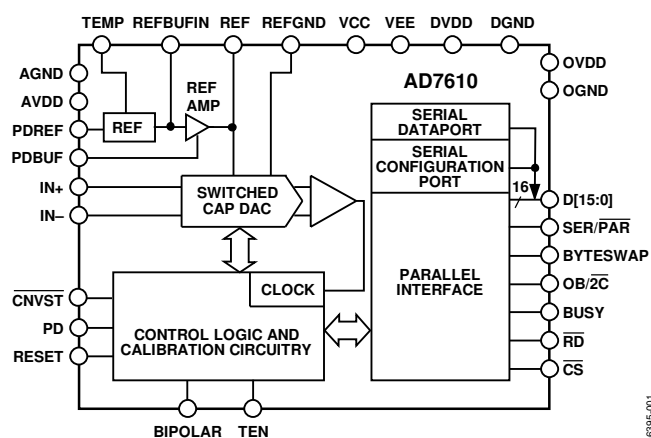


Figure 1.

Table 1. 48-Lead 14-/16-/18-Bit PulSAR Selection

Type	100 kSPS to 250 kSPS	500 kSPS to 570 kSPS	800 kSPS to 1000 kSPS	>1000 kSPS
Pseudo Differential	AD7651 AD7660 AD7661	AD7650 AD7652 AD7664 AD7666	AD7653 AD7667	
True Bipolar	AD7610 AD7663	AD7665	AD7612 AD7671 AD7951	
True Differential	AD7675	AD7676	AD7677	AD7621 AD7622 AD7623
18-Bit, True Differential	AD7678	AD7679	AD7674	AD7641 AD7643
Multichannel/ Simultaneous		AD7654 AD7655		

Rev. A

Document Feedback

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AD7610* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- AD7610 Evaluation Kit

DOCUMENTATION

Application Notes

- AN-1141: Powering a Dual Supply Precision ADC with Switching Regulators
- AN-742: Frequency Domain Response of Switched-Capacitor ADCs
- AN-931: Understanding PulSAR ADC Support Circuitry
- AN-932: Power Supply Sequencing

Data Sheet

- AD7610: 16-Bit, 250 kSPS, Unipolar/Bipolar Programmable Input PulSAR® ADC Data Sheet

Technical Books

- The Data Conversion Handbook, 2005

REFERENCE MATERIALS

Product Selection Guide

- SAR ADC & Driver Quick-Match Guide

Technical Articles

- MS-1779: Nine Often Overlooked ADC Specifications
- MS-2210: Designing Power Supplies for High Speed ADC

Tutorials

- MT-002: What the Nyquist Criterion Means to Your Sampled Data System Design
- MT-031: Grounding Data Converters and Solving the Mystery of "AGND" and "DGND"

DESIGN RESOURCES

- AD7610 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all AD7610 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

Submit feedback for this data sheet.

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REVISION HISTORY

12/12—Rev. 0 to Rev. A

Added Exposed Pad Note	8
Changes to Power Sequencing Section	23
Updated Outline Dimensions	31
Changes to Ordering Guide	31

10/06—Revision 0: Initial Version

SPECIFICATIONS

AVDD = DVDD = 5 V; OVDD = 2.7 V to 5.5 V; VCC = 15 V; VEE = -15 V; V_{REF} = 5 V; all specifications T_{MIN} to T_{MAX}, unless otherwise noted.

Table 2.

Parameter	Conditions/Comments	Min	Typ	Max	Unit
RESOLUTION		16			Bits
ANALOG INPUT					
Voltage Range, V _{IN}	V _{IN+} - V _{IN-} = 0 V to 5 V	-0.1		+5.1	V
	V _{IN+} - V _{IN-} = 0 V to 10 V	-0.1		+10.1	V
	V _{IN+} - V _{IN-} = ±5 V	-5.1		+5.1	V
	V _{IN+} - V _{IN-} = ±10 V	-10.1		+10.1	V
	V _{IN-} to AGND	-0.1		+0.1	V
Analog Input CMRR	f _{IN} = 100 kHz		75		dB
Input Current	V _{IN} = ±5 V, ±10 V @ 250 kSPS		100 ¹		μA
Input Impedance	See Analog Inputs section				
THROUGHPUT SPEED					
Complete Cycle				4	μs
Throughput Rate				250	kSPS
DC ACCURACY					
Integral Linearity Error ²		-1.5	±0.75	+1.5	LSB ³
No Missing Codes ²		16			Bits
Differential Linearity Error ²		-1		+1.5	LSB
Transition Noise			0.55		LSB
Zero Error (Unipolar or Bipolar)		-35		+35	LSB
Zero Error Temperature Drift			±1		ppm/°C
Bipolar Full-Scale Error		-50		+50	LSB
Unipolar Full-Scale Error		-70		+70	LSB
Full-Scale Error Temperature Drift			±1		ppm/°C
Power Supply Sensitivity	AVDD = 5 V ± 5%		3		LSB
AC ACCURACY					
Dynamic Range	V _{IN} = 0 V to 5 V, f _{IN} = 2 kHz, -60 dB	92.5	93.5		dB ⁴
	V _{IN} = 0 V to 10 V, ±5 V, f _{IN} = 2 kHz, -60 dB		94		dB
	V _{IN} = ±10 V, f _{IN} = 2 kHz, -60 dB		94.5		dB
Signal-to-Noise Ratio	V _{IN} = 0 V to 5 V, 0 V to 10 V, f _{IN} = 2 kHz	92	93		dB
	V _{IN} = ±5 V, ±10 V, f _{IN} = 2 kHz		94		dB
	V _{IN} = 0 V to 5 V, f _{IN} = 20 kHz		93.5		dB
Signal-to-(Noise + Distortion) (SINAD)	V _{IN} = ±5 V, f _{IN} = 2 kHz		92.5		dB
	V _{IN} = 0 V to 10 V, ±5 V, f _{IN} = 2 kHz		93		dB
	V _{IN} = ±10 V, f _{IN} = 2 kHz		93.5		dB
Total Harmonic Distortion	f _{IN} = 2 kHz		-107		dB
Spurious-Free Dynamic Range	f _{IN} = 2 kHz		107		dB
-3 dB Input Bandwidth	V _{IN} = 0 V to 5 V		650		kHz
Aperture Delay			2		ns
Aperture Jitter			5		ps rms
Transient Response	Full-scale step			500	ns
INTERNAL REFERENCE					
Output Voltage	PDREF = PDBUF = low	4.965	5.000	5.035	V
Temperature Drift	REF @ 25°C		±3		ppm/°C
Line Regulation	-40°C to +85°C		±15		ppm/V
Long-Term Drift	AVDD = 5 V ± 5%		50		ppm
Turn-On Settling Time	1000 hours		10		ms
REFERENCE BUFFER	C _{REF} = 22 μF				
REFBUF _{IN} Input Voltage Range	PDREF = high	2.4	2.5	2.6	V

Parameter	Conditions/Comments	Min	Typ	Max	Unit
EXTERNAL REFERENCE	PDREF = PDBUF = high				
Voltage Range	REF	4.75	5	AVDD + 0.1	V
Current Drain	250 kSPS throughput		30		μ A
TEMPERATURE PIN	@ 25°C				
Voltage Output			311		mV
Temperature Sensitivity			1		mV/°C
Output Resistance			4.33		k Ω
DIGITAL INPUTS					
Logic Levels					
V_{IL}		−0.3		+0.6	V
V_{IH}		2.1		OVDD + 0.3	V
I_{IL}		−1		+1	μ A
I_{IH}		−1		+1	μ A
DIGITAL OUTPUTS					
Data Format	Parallel or serial 16-bit				
Pipeline Delay ⁵					
V_{OL}	$I_{SINK} = 500 \mu$ A			0.4	V
V_{OH}	$I_{SOURCE} = -500 \mu$ A	OVDD − 0.6			V
POWER SUPPLIES					
Specified Performance					
AVDD		4.75 ⁶	5	5.25	V
DVDD		4.75	5	5.25	V
OVDD		2.7		5.25	V
VCC		7	15	15.75	V
VEE		−15.75	−15	0	V
Operating Current ^{7, 8}	@ 250 kSPS throughput				
AVDD					
With Internal Reference			8		mA
With Internal Reference Disabled			6.3		mA
DVDD			3.3		mA
OVDD			0.3		mA
VCC	VCC = 15 V, with internal reference buffer		1.4		mA
	VCC = 15 V		0.8		mA
VEE	VEE = −15 V		0.7		mA
Power Dissipation	@ 250 kSPS throughput				
With Internal Reference	PDREF = PDBUF = low		90	110	mW
With Internal Reference Disabled	PDREF = PDBUF = high		70	90	mW
In Power-Down Mode ⁹	PD = high		10		μ W
TEMPERATURE RANGE ¹⁰					
Specified Performance	T_{MIN} to T_{MAX}	−40		+85	°C

¹ With $V_{IN} = 0$ V to 5 V or 0 V to 10 V ranges, the input current is typically 40 μ A. In all input ranges, the input current scales with throughput. See the Analog Inputs section.

² Linearity is tested using endpoints, not best fit. All linearity is tested with an external 5 V reference.

³ LSB means least significant bit. All specifications in LSB do not include the error contributed by the reference.

⁴ All specifications in dB are referred to a full-scale range input, FSR. Tested with an input signal at 0.5 dB below full-scale, unless otherwise specified.

⁵ Conversion results are available immediately after completed conversion.

⁶ 4.75 V or $V_{REF} - 0.1$ V, whichever is larger.

⁷ Tested in parallel reading mode.

⁸ With internal reference, PDREF = PDBUF = low; with internal reference disabled, PDREF = PDBUF = high. With internal reference buffer, PDBUF = low.

⁹ With all digital inputs forced to OVDD.

¹⁰ Consult sales for extended temperature range.

TIMING SPECIFICATIONS

AVDD = DVDD = 5 V; OVDD = 2.7 V to 5.5 V; VCC = 15 V; VEE = -15 V; V_{REF} = 5 V; all specifications T_{MIN} to T_{MAX}, unless otherwise noted.

Table 3.

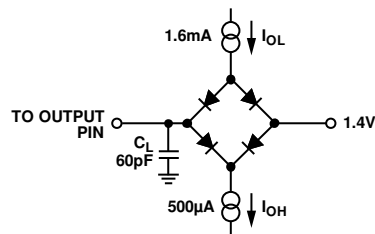
Parameter	Symbol	Min	Typ	Max	Unit
CONVERSION AND RESET (See Figure 33 and Figure 34)					
Convert Pulse Width	t ₁	10			ns
Time Between Conversions	t ₂	4			μs
CNVST Low to BUSY High Delay	t ₃			35	ns
BUSY High (Except Master Serial Read After Convert)	t ₄			1.45	μs
Aperture Delay	t ₅		2		ns
End of Conversion to BUSY Low Delay	t ₆	10			ns
Conversion Time	t ₇			1.45	μs
Acquisition Time	t ₈	380			ns
RESET Pulse Width	t ₉	10			ns
PARALLEL INTERFACE MODES (See Figure 35 and Figure 37)					
CNVST Low to DATA Valid Delay	t ₁₀			1.41	μs
DATA Valid to BUSY Low Delay	t ₁₁	20			ns
Bus Access Request to DATA Valid	t ₁₂			40	ns
Bus Relinquish Time	t ₁₃	2		15	ns
MASTER SERIAL INTERFACE MODES ¹ (See Figure 39 and Figure 40)					
$\overline{\text{CS}}$ Low to SYNC Valid Delay	t ₁₄			10	ns
$\overline{\text{CS}}$ Low to Internal SDCLK Valid Delay ¹	t ₁₅			10	ns
$\overline{\text{CS}}$ Low to SDOUT Delay	t ₁₆			10	ns
CNVST Low to SYNC Delay, Read During Convert	t ₁₇		560		ns
SYNC Asserted to SDCLK First Edge Delay	t ₁₈	3			ns
Internal SDCLK Period ²	t ₁₉	30		45	ns
Internal SDCLK High ²	t ₂₀	15			ns
Internal SDCLK Low ²	t ₂₁	10			ns
SDOUT Valid Setup Time ²	t ₂₂	4			ns
SDOUT Valid Hold Time ²	t ₂₃	5			ns
SDCLK Last Edge to SYNC Delay ²	t ₂₄	5			ns
$\overline{\text{CS}}$ High to SYNC HI-Z	t ₂₅			10	ns
$\overline{\text{CS}}$ High to Internal SDCLK HI-Z	t ₂₆			10	ns
$\overline{\text{CS}}$ High to SDOUT HI-Z	t ₂₇			10	ns
BUSY High in Master Serial Read After Convert ²	t ₂₈		See Table 4		
CNVST Low to SYNC Delay, Read After Convert	t ₂₉		1.31		μs
SYNC Deasserted to BUSY Low Delay	t ₃₀		25		ns
SLAVE SERIAL/SERIAL CONFIGURATION INTERFACE MODES ¹ (See Figure 42, Figure 43, and Figure 45)					
External SDCLK, SCCLK Setup Time	t ₃₁	5			ns
External SDCLK Active Edge to SDOUT Delay	t ₃₂	2		18	ns
SDIN/SCIN Setup Time	t ₃₃	5			ns
SDIN/SCIN Hold Time	t ₃₄	5			ns
External SDCLK/SCCLK Period	t ₃₅	25			ns
External SDCLK/SCCLK High	t ₃₆	10			ns
External SDCLK/SCCLK Low	t ₃₇	10			ns

¹ In serial interface modes, the SDSYNC, SDSCLK, and SDOUT timings are defined with a maximum load C_L of 10 pF; otherwise, the load is 60 pF maximum.

² In serial master read during convert mode. See Table 4 for serial mode read after convert mode.

Table 4. Serial Clock Timings in Master Read After Convert Mode

DIVSCLK[1] DIVSCLK[0]	Symbol	0 0	0 1	1 0	1 1	Unit
SYNC to SDCLK First Edge Delay Minimum	t_{18}	3	20	20	20	ns
Internal SDCLK Period Minimum	t_{19}	30	60	120	240	ns
Internal SDCLK Period Maximum	t_{19}	45	90	180	360	ns
Internal SDCLK High Minimum	t_{20}	15	30	60	120	ns
Internal SDCLK Low Minimum	t_{21}	10	25	55	115	ns
SDOUT Valid Setup Time Minimum	t_{22}	4	20	20	20	ns
SDOUT Valid Hold Time Minimum	t_{23}	5	8	35	90	ns
SDCLK Last Edge to SYNC Delay Minimum	t_{24}	5	7	35	90	ns
BUSY High Width Maximum	t_{28}	2.25	3.00	4.40	7.30	μ s



NOTES

1. IN SERIAL INTERFACE MODES, THE SYNC, SCLK, AND SDOUT ARE DEFINED WITH A MAXIMUM LOAD C_L OF 10pF; OTHERWISE, THE LOAD IS 60pF MAXIMUM.

Figure 2. Load Circuit for Digital Interface Timing, SDOUT, SYNC, and SCLK Outputs, $C_L = 10$ pF

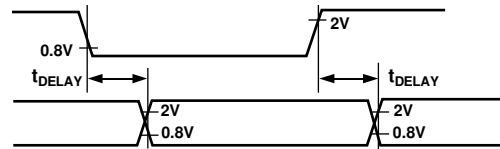


Figure 3. Voltage Reference Levels for Timing

ABSOLUTE MAXIMUM RATINGS

Table 5.

Parameter	Rating
Analog Inputs/Outputs IN+, IN ⁻¹ to AGND REF, REFBUF _{IN} , TEMP, REFGND to AGND	VEE – 0.3 V to VCC + 0.3 V AVDD + 0.3 V to AGND – 0.3 V
Ground Voltage Differences AGND, DGND, OGND	±0.3 V
Supply Voltages AVDD, DVDD, OVDD AVDD to DVDD, AVDD to OVDD DVDD to OVDD VCC to AGND, DGND VEE to GND	–0.3 V to +7 V ±7 V ±7 V –0.3 V to +16.5 V +0.3 V to –16.5 V
Digital Inputs PDREF, PDBUF ²	–0.3 V to OVDD + 0.3 V ±20 mA
Internal Power Dissipation ³	700 mW
Internal Power Dissipation ⁴	2.5 W
Junction Temperature	125°C
Storage Temperature Range	–65°C to +125°C

¹ See the Analog Inputs section.² See the Voltage Reference Input section.³ Specification is for the device in free air: 48-Lead LQFP; $\theta_{JA} = 91^{\circ}\text{C/W}$,
 $\theta_{JC} = 30^{\circ}\text{C/W}$.⁴ Specification is for the device in free air: 48-Lead LFCSP; $\theta_{JA} = 26^{\circ}\text{C/W}$.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

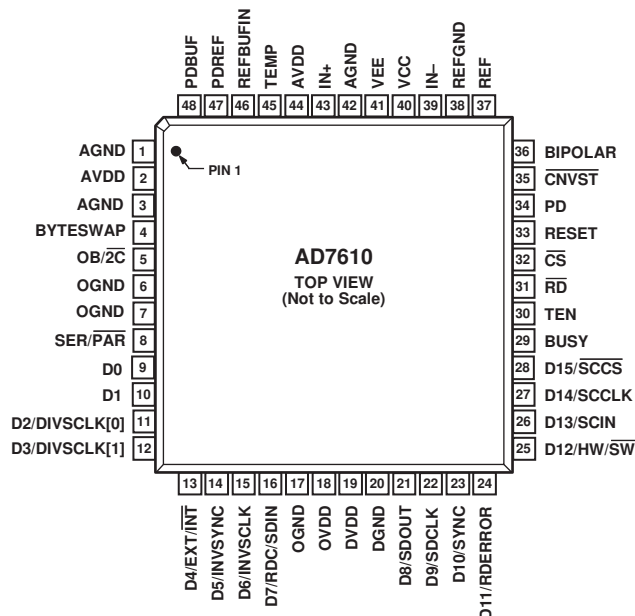
ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



NOTES
1. FOR THE LEAD FRAME CHIP SCALE PACKAGE (LFCSP), THE EXPOSED PAD SHOULD BE CONNECTED TO VEE. THIS CONNECTION IS NOT REQUIRED TO MEET THE ELECTRICAL PERFORMANCES.

06395-004

Figure 4. Pin Configuration

Table 6. Pin Function Descriptions

Pin No.	Mnemonic	Type ¹	Description
1, 3, 42	AGND	P	Analog Power Ground Pins. Ground reference point for all analog I/O. All analog I/O should be referenced to AGND and should be connected to the analog ground plane of the system. In addition, the AGND, DGND, and OGND voltages should be at the same potential.
2, 44	AVDD	P	Analog Power Pins. Nominally 4.75 V to 5.25 V and decoupled with 10 μ F and 100 nF capacitors.
4	BYTESWAP	DI	Parallel Mode Selection (8-Bit/16-Bit). When high, the LSB is output on D[15:8] and the MSB is output on D[7:0]; when low, the LSB is output on D[7:0] and the MSB is output on D[15:8].
5	OB/ $\overline{2C}$	DI ²	Straight Binary/Binary Twos Complement Output. When high, the digital output is straight binary. When low, the MSB is inverted resulting in a twos complement output from its internal shift register.
6, 7, 17	OGND	P	Input/Output Interface Digital Power Ground. Ground reference point for digital outputs. Should be connected to the system digital ground ideally at the same potential as AGND and DGND.
8	SER/ $\overline{PAR}$	DI	Serial/Parallel Selection Input. When SER/ $\overline{PAR}$ = low, the parallel mode is selected. When SER/ $\overline{PAR}$ = high, the serial modes are selected. Some bits of the data bus are used as a serial port and the remaining data bits are high impedance outputs.
9, 10	D[0:1]	DO	Bit 0 and Bit 1 of the parallel port data output bus. These pins are always outputs regardless of the state of SER/ $\overline{PAR}$.
11, 12	D[2:3] or DIVSCLK[0:1]	DI/O	In parallel mode, these outputs are used as Bit 2 and Bit 3 of the parallel port data output bus. Serial Data Division Clock Selection. In serial master read after convert mode (SER/ $\overline{PAR}$ = high, EXT/ $\overline{INT}$ = low, RDC/SDIN = low) these inputs can be used to slow down the internally generated serial data clock that clocks the data output. In other serial modes, these pins are high impedance outputs.
13	D4 or EXT/ $\overline{INT}$	DI/O	In parallel mode, this output is used as Bit 4 of the parallel port data output bus. Serial Data Clock Source Select. In serial mode, this input is used to select the internally generated (master) or external (slave) serial data clock for the AD7610 output data. When EXT/ $\overline{INT}$ = low, master mode; the internal serial data clock is selected on SDCLK output. When EXT/ $\overline{INT}$ = high, slave mode; the output data is synchronized to an external clock signal (gated by $\overline{CS}$) connected to the SDCLK input.

Pin No.	Mnemonic	Type ¹	Description
14	D5 or INVSYN	DI/O	In parallel mode, this output is used as Bit 5 of the parallel port data output bus. Serial Data Invert Sync Select. In serial master mode ($\overline{\text{SER/}\overline{\text{PAR}}} = \text{high}$, $\overline{\text{EXT/}\overline{\text{INT}}} = \text{low}$). This input is used to select the active state of the SYNC signal. When INVSYN = low, SYNC is active high. When INVSYN = high, SYNC is active low.
15	D6 or INVSCLK	DI/O	In parallel mode, this output is used as Bit 6 of the parallel port data output bus. In all serial modes, invert SDCLK/SCCLK select. This input is used to invert both SDCLK and SCCLK. When INVSCLK = low, the rising edge of SDCLK/SCCLK are used. When INVSCLK = high, the falling edge of SDCLK/SCCLK are used.
16	D7 or RDC or SDIN	DI/O	In parallel mode, this output is used as Bit 7 of the parallel port data output bus. Serial Data Read During Convert. In serial master mode ($\overline{\text{SER/}\overline{\text{PAR}}} = \text{high}$, $\overline{\text{EXT/}\overline{\text{INT}}} = \text{low}$) RDC is used to select the read mode. See the Master Serial Interface section. When RDC = low, the current result is read after conversion. Note the maximum throughput is not attainable in this mode. When RDC = high, the previous conversion result is read during the current conversion. Serial Data In. In serial slave mode ($\overline{\text{SER/}\overline{\text{PAR}}} = \text{high}$, $\overline{\text{EXT/}\overline{\text{INT}}} = \text{high}$) SDIN can be used as a data input to daisy-chain the conversion results from two or more ADCs onto a single SDOUT line. The digital data level on SDIN is output on SDOUT with a delay of 16 SDCLK periods after the initiation of the read sequence.
18	OVDD	P	Input/Output Interface Digital Power. Nominally at the same supply as the supply of the host interface 2.5 V, 3 V, or 5 V and decoupled with 10 μF and 100 nF capacitors.
19	DVDD	P	Digital Power. Nominally at 4.75 V to 5.25 V and decoupled with 10 μF and 100 nF capacitors. Can be supplied from AVDD.
20	DGND	P	Digital Power Ground. Ground reference point for digital outputs. Should be connected to system digital ground ideally at the same potential as AGND and OGND.
21	D8 or SDOUT	DO	In parallel mode, this output is used as Bit 8 of the parallel port data output bus. Serial Data output. In all serial modes this pin is used as the serial data output synchronized to SDCLK. Conversion results are stored in an on-chip register. The AD7610 provides the conversion result, MSB first, from its internal shift register. The data format is determined by the logic level of $\text{OB}/\overline{2\text{C}}$. When $\overline{\text{EXT/}\overline{\text{INT}}} = \text{low}$, (master mode) SDOUT is valid on both edges of SDCLK. When $\overline{\text{EXT/}\overline{\text{INT}}} = \text{high}$ (slave mode). When INVSCLK = low, SDOUT is updated on SDCLK rising edge. When INVSCLK = high, SDOUT is updated on SDCLK falling edge.
22	D9 or SDCLK	DI/O	In parallel mode, this output is used as Bit 9 of the parallel port data output bus. Serial Data Clock. In all serial modes, this pin is used as the serial data clock input or output, dependent on the logic state of the $\overline{\text{EXT/}\overline{\text{INT}}}$ pin. The active edge where the data SDOUT is updated depends on the logic state of the INVSCLK pin.
23	D10 or SYNC	DO	In parallel mode, this output is used as Bit 10 of the parallel port data output bus. Serial Data Frame Synchronization. In serial master mode ($\overline{\text{SER/}\overline{\text{PAR}}} = \text{high}$, $\overline{\text{EXT/}\overline{\text{INT}}} = \text{low}$), this output is used as a digital output frame synchronization for use with the internal data clock. When a read sequence is initiated and INVSYN = low, SYNC is driven high and remains high while the SDOUT output is valid. When a read sequence is initiated and INVSYN = high, SYNC is driven low and remains low while the SDOUT output is valid.
24	D11 or RDERROR	DO	In parallel mode, this output is used as Bit 11 of the parallel port data output bus. Serial Data Read Error. In serial slave mode ($\overline{\text{SER/}\overline{\text{PAR}}} = \text{high}$, $\overline{\text{EXT/}\overline{\text{INT}}} = \text{high}$), this output is used as an incomplete data read error flag. If a data read is started and not completed when the current conversion is complete, the current data is lost and RDERROR is pulsed high.
25	D12 or $\overline{\text{HW/}\overline{\text{SW}}}$	DI/O	In parallel mode, this output is used as Bit 12 of the parallel port data output bus. Serial Configuration Hardware/Software Select. In serial mode, this input is used to configure the AD7610 by hardware or software. See the Hardware Configuration section and Software Configuration section. When $\overline{\text{HW/}\overline{\text{SW}}} = \text{low}$, the AD7610 is configured through software using the serial configuration register. When $\overline{\text{HW/}\overline{\text{SW}}} = \text{high}$, the AD7610 is configured through dedicated hardware input pins.
26	D13 or SCIN	DI/O	In parallel mode, this output is used as Bit 13 of the parallel port data output bus. Serial Configuration Data Input. In serial software configuration mode ($\overline{\text{SER/}\overline{\text{PAR}}} = \text{high}$, $\overline{\text{HW/}\overline{\text{SW}}} = \text{low}$) this input is used to serially write in, MSB first, the configuration data into the serial configuration register. The data on this input is latched with SCCLK. See the Software Configuration section.

Pin No.	Mnemonic	Type ¹	Description															
27	D14 or SCCLK	DI/O	In parallel mode, this output is used as Bit 14 of the parallel port data output bus. Serial Configuration Clock. In serial software configuration mode (SER/ $\overline{\text{PAR}}$ = high, HW/ $\overline{\text{SW}}$ = low) this input is used to clock in the data on SCIN. The active edge where the data SCIN is updated depends on the logic state of the INVSCCLK pin. See the Software Configuration section.															
28	D15 or $\overline{\text{SCCS}}$	DI/O	In parallel mode, this output is used as Bit 15 of the parallel port data output bus. Serial Configuration Chip Select. In serial software configuration mode (SER/ $\overline{\text{PAR}}$ = high, HW/ $\overline{\text{SW}}$ = low) this input enables the serial configuration port. See the Software Configuration section.															
29	BUSY	DO	Busy Output. Transitions high when a conversion is started, and remains high until the conversion is complete and the data is latched into the on-chip shift register. The falling edge of BUSY can be used as a data ready clock signal. Note that in master read after convert mode (SER/ $\overline{\text{PAR}}$ = high, EXT/ $\overline{\text{INT}}$ = low, RDC = low) the busy time changes according to Table 4.															
30	TEN	DI ²	Input Range Select. Used in conjunction with BIPOLAR per the following: <table><tr><th>Input Range</th><th>BIPOLAR</th><th>TEN</th></tr><tr><td>0 V to 5 V</td><td>Low</td><td>Low</td></tr><tr><td>0 V to 10 V</td><td>Low</td><td>High</td></tr><tr><td>±5 V</td><td>High</td><td>Low</td></tr><tr><td>±10 V</td><td>High</td><td>High</td></tr></table>	Input Range	BIPOLAR	TEN	0 V to 5 V	Low	Low	0 V to 10 V	Low	High	±5 V	High	Low	±10 V	High	High
Input Range	BIPOLAR	TEN																
0 V to 5 V	Low	Low																
0 V to 10 V	Low	High																
±5 V	High	Low																
±10 V	High	High																
31	$\overline{\text{RD}}$	DI	Read Data. When $\overline{\text{CS}}$ and $\overline{\text{RD}}$ are both low, the interface parallel or serial output bus is enabled.															
32	$\overline{\text{CS}}$	DI	Chip Select. When $\overline{\text{CS}}$ and $\overline{\text{RD}}$ are both low, the interface parallel or serial output bus is enabled. $\overline{\text{CS}}$ is also used to gate the external clock in slave serial mode (not used for serial programmable port).															
33	RESET	DI	Reset Input. When high, reset the AD7610. Current conversion, if any, is aborted. The falling edge of RESET resets the data outputs to all zero's (with OB/ $\overline{2\text{C}}$ = high) and clears the configuration register. See the Digital Interface section. If not used, this pin can be tied to OGND.															
34	PD	DI ²	Power-Down Input. When PD = high, power down the ADC. Power consumption is reduced and conversions are inhibited after the current one is completed. The digital interface remains active during power down.															
35	$\overline{\text{CNVST}}$	DI	Conversion Start. A falling edge on $\overline{\text{CNVST}}$ puts the internal sample-and-hold into the hold state and initiates a conversion.															
36	BIPOLAR	DI ²	Input Range Select. See description for Pin 30.															
37	REF	AI/O	Reference Input/Output. When PDREF/PDBUF = low, the internal reference and buffer are enabled, producing 5 V on this pin. When PDREF/PDBUF = high, the internal reference and buffer are disabled, allowing an externally supplied voltage reference up to AVDD volts. Decoupling with at least a 22 μF is required with or without the internal reference and buffer. See the Reference Decoupling section.															
38	REFGND	AI	Reference Input Analog Ground. Connected to analog ground plane.															
39	IN–	AI	Analog Input Ground Sense. Should be connected to the analog ground plane or to a remote sense ground.															
40	VCC	P	High Voltage Positive Supply. Normally +7 V to +15 V.															
41	VEE	P	High Voltage Negative Supply. Normally 0 V to –15 V (0 V in unipolar ranges).															
43	IN+	AI	Analog Input. Referenced to IN–.															
45	TEMP	AO	Temperature Sensor Analog Output. Enabled when the internal reference is turned on (PDREF = PDBUF = low). See the Temperature Sensor section.															
46	REFBUFIN	AI	Reference Buffer Input. When using an external reference with the internal reference buffer (PDBUF = low, PDREF = high), applying 2.5 V on this pin produces 5 V on the REF pin. See the Voltage Reference Input section.															
47	PDREF	DI	Internal Reference Power-Down Input. When low, the internal reference is enabled. When high, the internal reference is powered down, and an external reference must be used.															
48	PDBUF	DI	Internal Reference Buffer Power-Down Input. When low, the buffer is enabled (must be low when using internal reference). When high, the buffer is powered-down.															
49	EPAD ³	NC	Exposed Pad. The exposed pad is not connected internally. It is recommended that the pad be soldered to VEE.															

¹ AI = analog input; AI/O = bidirectional analog; AO = analog output; DI = digital input; DI/O = bidirectional digital; DO = digital output; P = power.

² In serial configuration mode ($\overline{\text{SER}}/\overline{\text{PAR}} = \text{high}$, $\text{HW}/\overline{\text{SW}} = \text{low}$), this input is programmed with the serial configuration register and this pin is a don't care. See the Hardware Configuration section and Software Configuration section.

³ LFCSP_VQ package only.

TYPICAL PERFORMANCE CHARACTERISTICS

AVDD = DVDD = 5 V; OVDD = 5 V; VCC = 15 V; VEE = -15 V; V_{REF} = 5 V; T_A = 25°C.

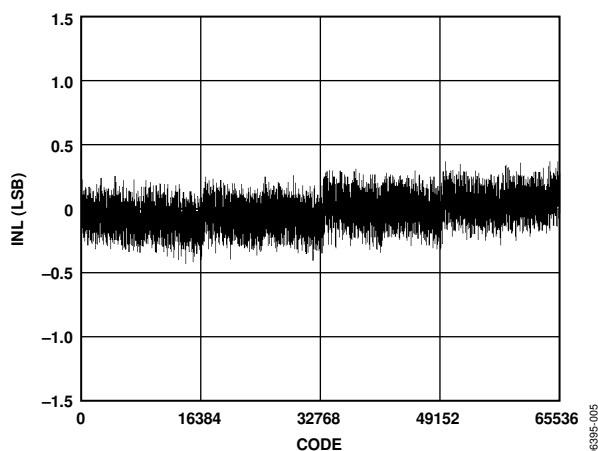


Figure 5. Integral Nonlinearity vs. Code

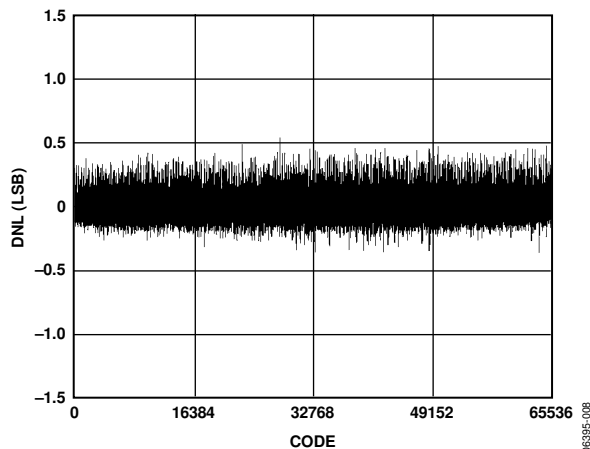


Figure 8. Differential Nonlinearity vs. Code

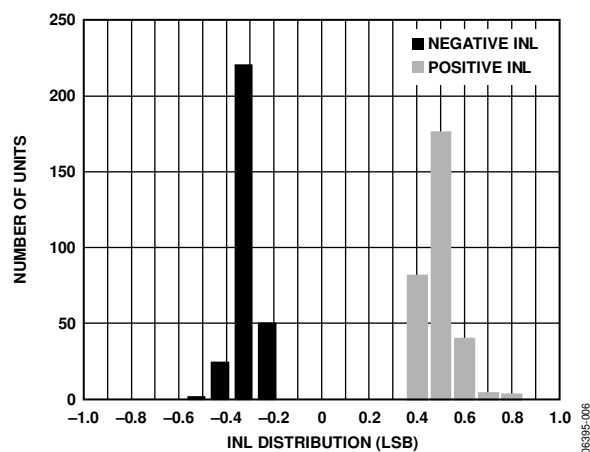


Figure 6. Integral Nonlinearity Distribution (296 Devices)

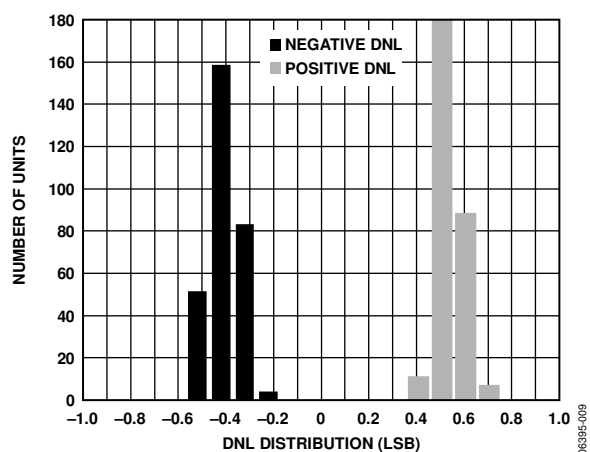


Figure 9. Differential Nonlinearity Distribution (296 Devices)

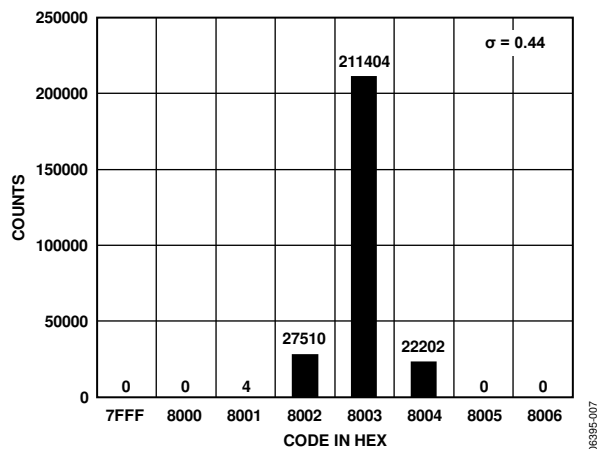


Figure 7. Histogram of 261,120 Conversions of a DC Input at the Code Center

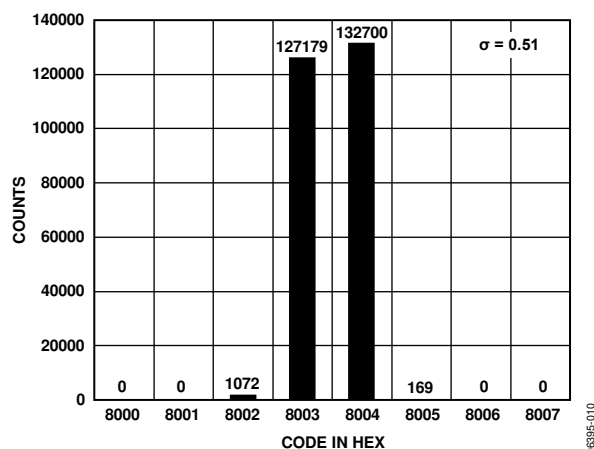


Figure 10. Histogram of 261,120 Conversions of a DC Input at the Code Transition

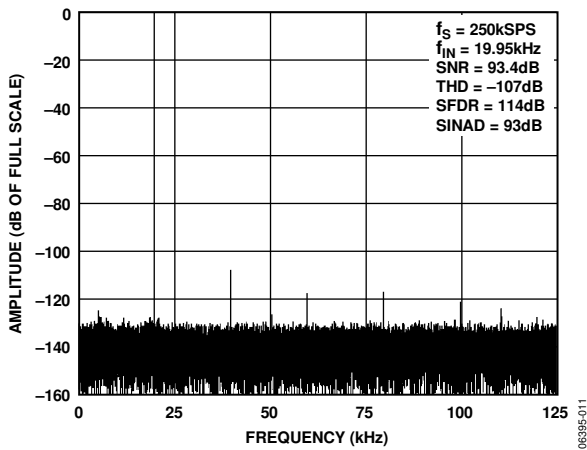


Figure 11. FFT 20 kHz

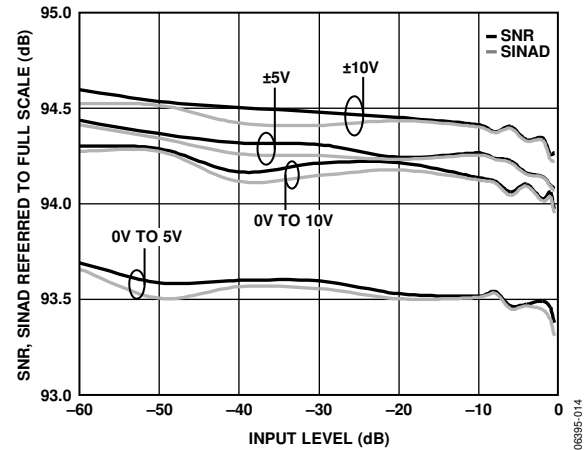


Figure 14. SNR and SINAD vs. Input Level (Referred to Full Scale)

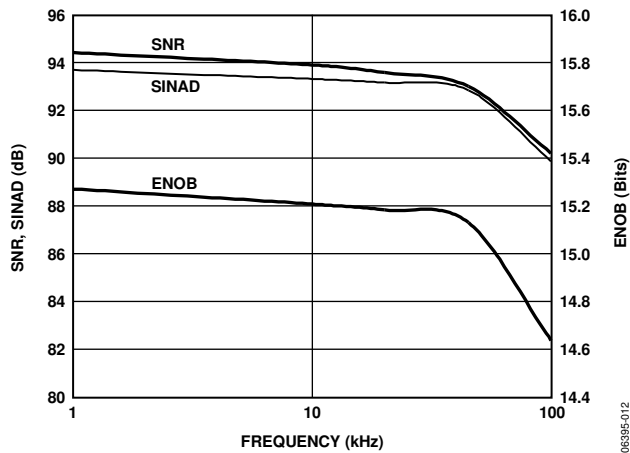


Figure 12. SNR, SINAD, and ENOB vs. Frequency

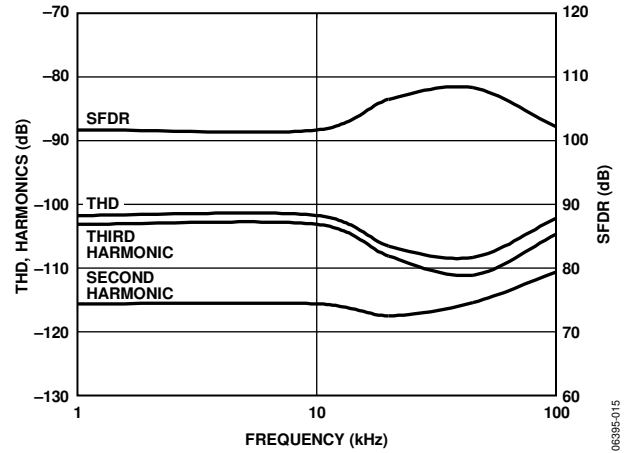


Figure 15. THD, Harmonics, and SFDR vs. Frequency

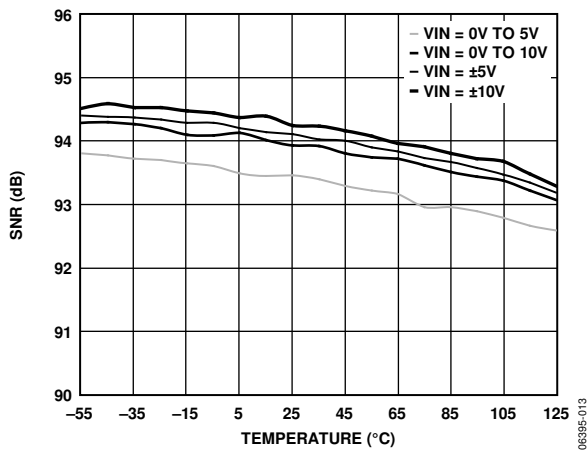


Figure 13. SNR vs. Temperature

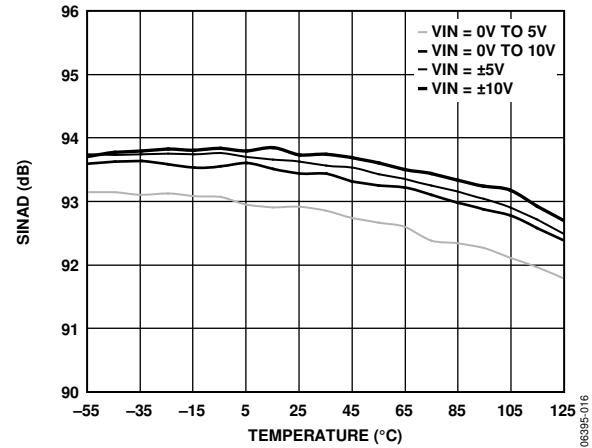


Figure 16. SINAD vs. Temperature

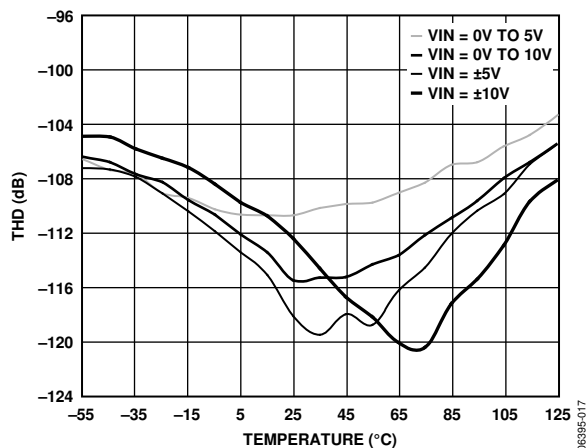


Figure 17. THD vs. Temperature

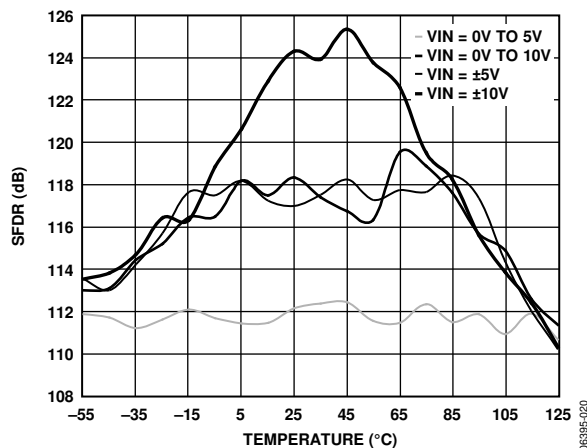


Figure 20. SFDR vs. Temperature (Excludes Harmonics)

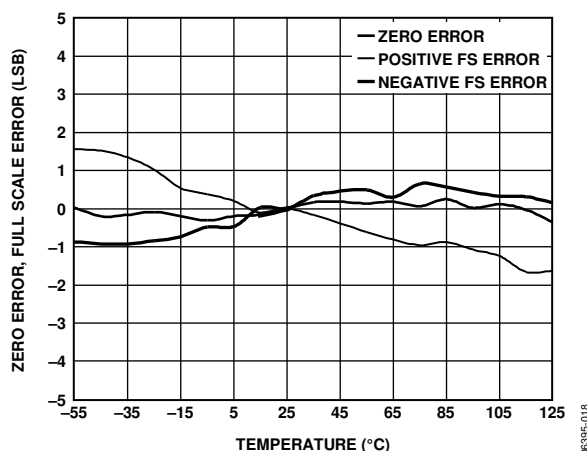


Figure 18. Zero Error, Positive and Negative Full Scale vs. Temperature

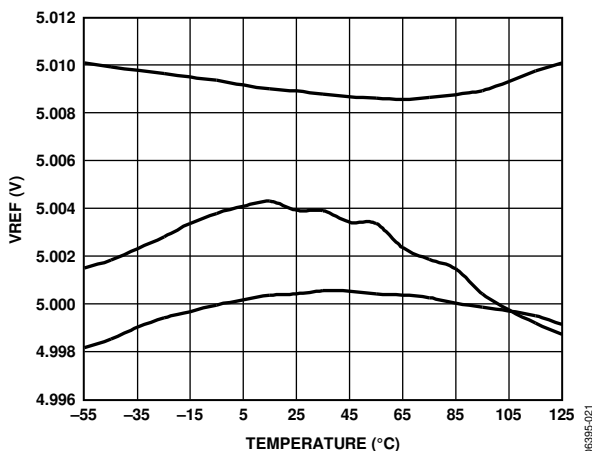


Figure 21. Typical Reference Voltage Output vs. Temperature (3 Devices)

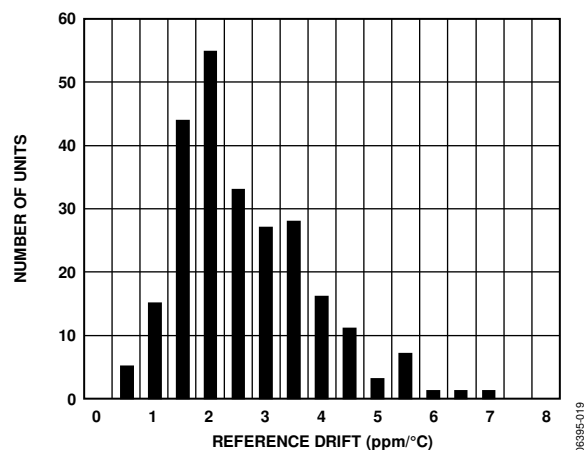


Figure 19. Reference Voltage Temperature Coefficient Distribution (247 Devices)

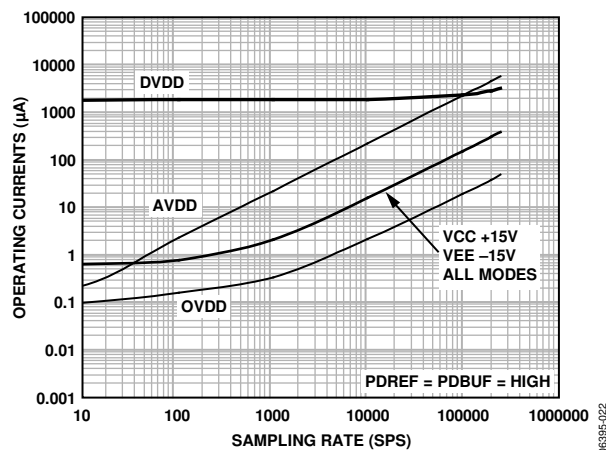


Figure 22. Operating Currents vs. Sample Rate

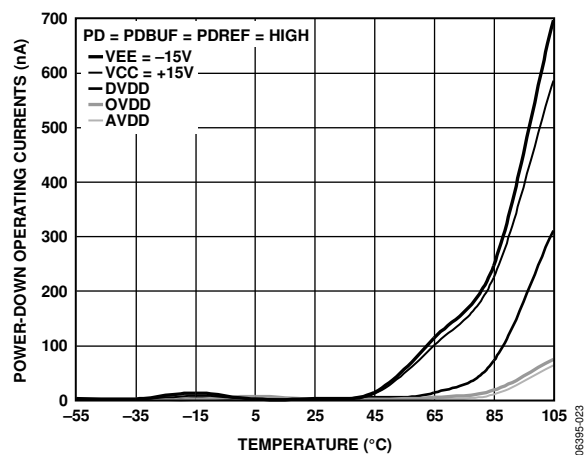


Figure 23. Power-Down Operating Currents vs. Temperature

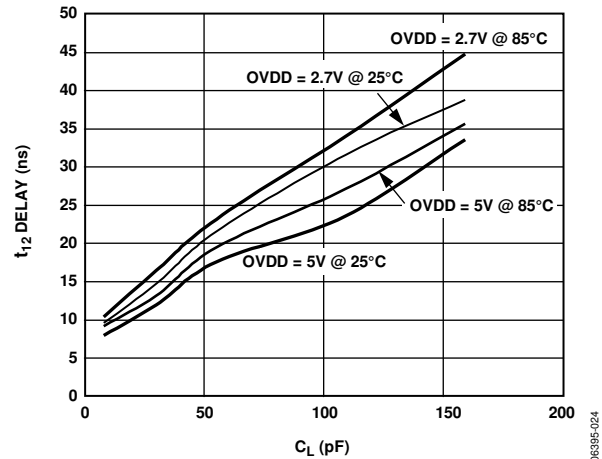


Figure 24. Typical Delay vs. Load Capacitance C_L

TERMINOLOGY

Least Significant Bit (LSB)

The least significant bit, or LSB, is the smallest increment that can be represented by a converter. For an analog-to-digital converter with N bits of resolution, the LSB expressed in volts is

$$LSB(V) = \frac{V_{INP-P}(max)}{2^N}$$

Integral Nonlinearity Error (INL)

Linearity error refers to the deviation of each individual code from a line drawn from negative full-scale through positive full-scale. The point used as negative full-scale occurs a $\frac{1}{2}$ LSB before the first code transition. Positive full-scale is defined as a level $1\frac{1}{2}$ LSBs beyond the last code transition. The deviation is measured from the middle of each code to the true straight line.

Differential Nonlinearity Error (DNL)

In an ideal ADC, code transitions are 1 LSB apart. Differential nonlinearity is the maximum deviation from this ideal value. It is often specified in terms of resolution for which no missing codes are guaranteed.

Bipolar Zero Error

The difference between the ideal midscale input voltage (0 V) and the actual voltage producing the midscale output code.

Unipolar Offset Error

The first transition should occur at a level $\frac{1}{2}$ LSB above analog ground. The unipolar offset error is the deviation of the actual transition from that point.

Full-Scale Error

The last transition (from 111...10 to 111...11) should occur for an analog voltage $1\frac{1}{2}$ LSB below the nominal full-scale. The full-scale error is the deviation in LSB (or % of full-scale range) of the actual level of the last transition from the ideal level and includes the effect of the offset error. Closely related is the gain error (also in LSB or % of full-scale range), which does not include the effects of the offset error.

Dynamic Range

Dynamic range is the ratio of the rms value of the full-scale to the rms noise measured for an input typically at -60 dB. The value for dynamic range is expressed in decibels.

Signal-to-Noise Ratio (SNR)

SNR is the ratio of the rms value of the actual input signal to the rms sum of all other spectral components below the Nyquist frequency, excluding harmonics and dc. The value for SNR is expressed in decibels.

Total Harmonic Distortion (THD)

THD is the ratio of the rms sum of the first five harmonic components to the rms value of a full-scale input signal and is expressed in decibels.

Signal-to-(Noise + Distortion) Ratio (SINAD)

SINAD is the ratio of the rms value of the actual input signal to the rms sum of all other spectral components below the Nyquist frequency, including harmonics but excluding dc. The value for SINAD is expressed in decibels.

Spurious-Free Dynamic Range (SFDR)

The difference, in decibels (dB), between the rms amplitude of the input signal and the peak spurious signal.

Effective Number of Bits (ENOB)

ENOB is a measurement of the resolution with a sine wave input. It is related to SINAD and is expressed in bits by

$$ENOB = [(SINAD_{dB} - 1.76)/6.02]$$

Aperture Delay

Aperture delay is a measure of the acquisition performance measured from the falling edge of the CNVST input to when the input signal is held for a conversion.

Transient Response

The time required for the AD7610 to achieve its rated accuracy after a full-scale step function is applied to its input.

Reference Voltage Temperature Coefficient

Reference voltage temperature coefficient is derived from the typical shift of output voltage at 25°C on a sample of parts at the maximum and minimum reference output voltage (V_{REF}) measured at T_{MIN} , $T(25^{\circ}\text{C})$, and T_{MAX} . It is expressed in ppm/ $^{\circ}\text{C}$ as

$$TCV_{REF}(\text{ppm}/^{\circ}\text{C}) = \frac{V_{REF}(Max) - V_{REF}(Min)}{V_{REF}(25^{\circ}\text{C}) \times (T_{MAX} - T_{MIN})} \times 10^6$$

where:

$V_{REF}(Max)$ = maximum V_{REF} at T_{MIN} , $T(25^{\circ}\text{C})$, or T_{MAX} .

$V_{REF}(Min)$ = minimum V_{REF} at T_{MIN} , $T(25^{\circ}\text{C})$, or T_{MAX} .

$V_{REF}(25^{\circ}\text{C})$ = V_{REF} at 25°C .

T_{MAX} = $+85^{\circ}\text{C}$.

T_{MIN} = -40°C .

THEORY OF OPERATION

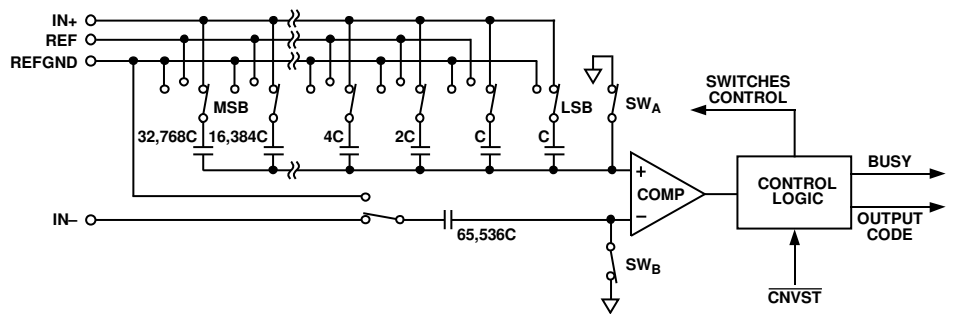


Figure 25. ADC Simplified Schematic

OVERVIEW

The AD7610 is a very fast, low power, precise, 16-bit analog-to-digital converter (ADC) using successive approximation capacitive digital-to-analog converter (CDAC) architecture.

The AD7610 can be configured at any time for one of four input ranges with inputs in parallel and serial hardware modes or by a dedicated write only, SPI-compatible interface via a configuration register in serial software mode. The AD7610 uses Analog Device's patented iCMOS high voltage process to accommodate 0 to 5 V, 0 to 10 V, ± 5 V, and ± 10 V input ranges without the use of conventional thin films. Only one acquisition cycle, t_{a} , is required for the inputs to latch to the correct configuration. Resetting or power cycling is not required for reconfiguring the ADC.

The AD7610 is capable of converting 250,000 samples per second (250 kSPS) and power consumption scales linearly with throughput making it useful for battery powered systems.

The AD7610 provides the user with an on-chip track-and-hold, successive approximation ADC that does not exhibit any pipeline or latency, making it ideal for multiple multiplexed channel applications.

For unipolar input ranges, the AD7610 typically requires three supplies; VCC, AVDD (which can supply DVDD), and OVDD which can be interfaced to either 5 V, 3.3 V, or 2.5 V digital logic. For bipolar input ranges, the AD7610 requires the use of the additional VEE supply.

The device is housed in Pb-free, 48-lead LQFP or tiny LFCSP 7 mm $\times$ 7 mm packages that combine space savings with flexibility. In addition, the AD7610 can be configured as either a parallel or serial SPI-compatible interface.

CONVERTER OPERATION

The AD7610 is a successive approximation ADC based on a charge redistribution DAC. Figure 25 shows the simplified schematic of the ADC. The CDAC consists of two identical arrays of 16 binary weighted capacitors, which are connected to the two comparator inputs.

During the acquisition phase, terminals of the array tied to the comparator's input are connected to AGND via SW+ and SW-. All independent switches are connected to the analog inputs. Thus, the capacitor arrays are used as sampling capacitors and acquire the analog signal on IN+ and IN- inputs. A conversion phase is initiated once the acquisition phase is complete and the CNVST input goes low. When the conversion phase begins, SW+ and SW- are opened first. The two capacitor arrays are then disconnected from the inputs and connected to the REFGND input. Therefore, the differential voltage between the inputs (IN+ and IN-) captured at the end of the acquisition phase is applied to the comparator inputs, causing the comparator to become unbalanced. By switching each element of the capacitor array between REFGND and REF, the comparator input varies by binary weighted voltage steps ($V_{\text{REF}}/2$, $V_{\text{REF}}/4$ through $V_{\text{REF}}/65536$). The control logic toggles these switches, starting with the MSB first, in order to bring the comparator back into a balanced condition.

After the completion of this process, the control logic generates the ADC output code and brings the BUSY output low.

TRANSFER FUNCTIONS

Using the $\overline{\text{OB/2C}}$ digital input or via the configuration register, the AD7610 offers two output codings: straight binary and twos complement. See Figure 26 and Table 7 for the ideal transfer characteristic and digital output codes for the different analog input ranges, V_{IN} . Note that when using the configuration register, the $\overline{\text{OB/2C}}$ input is a don't care and should be tied to either high or low.

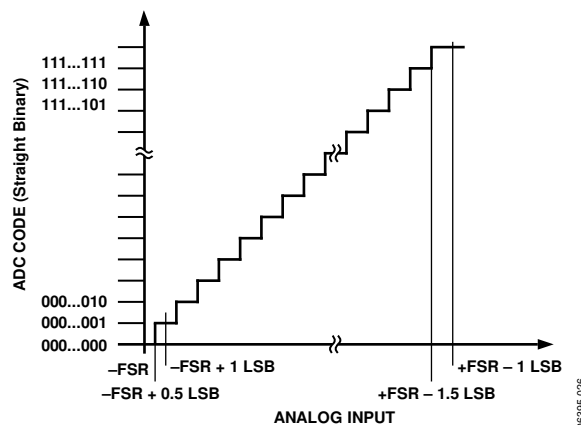


Figure 26. ADC Ideal Transfer Function

Table 7. Output Codes and Ideal Input Voltages

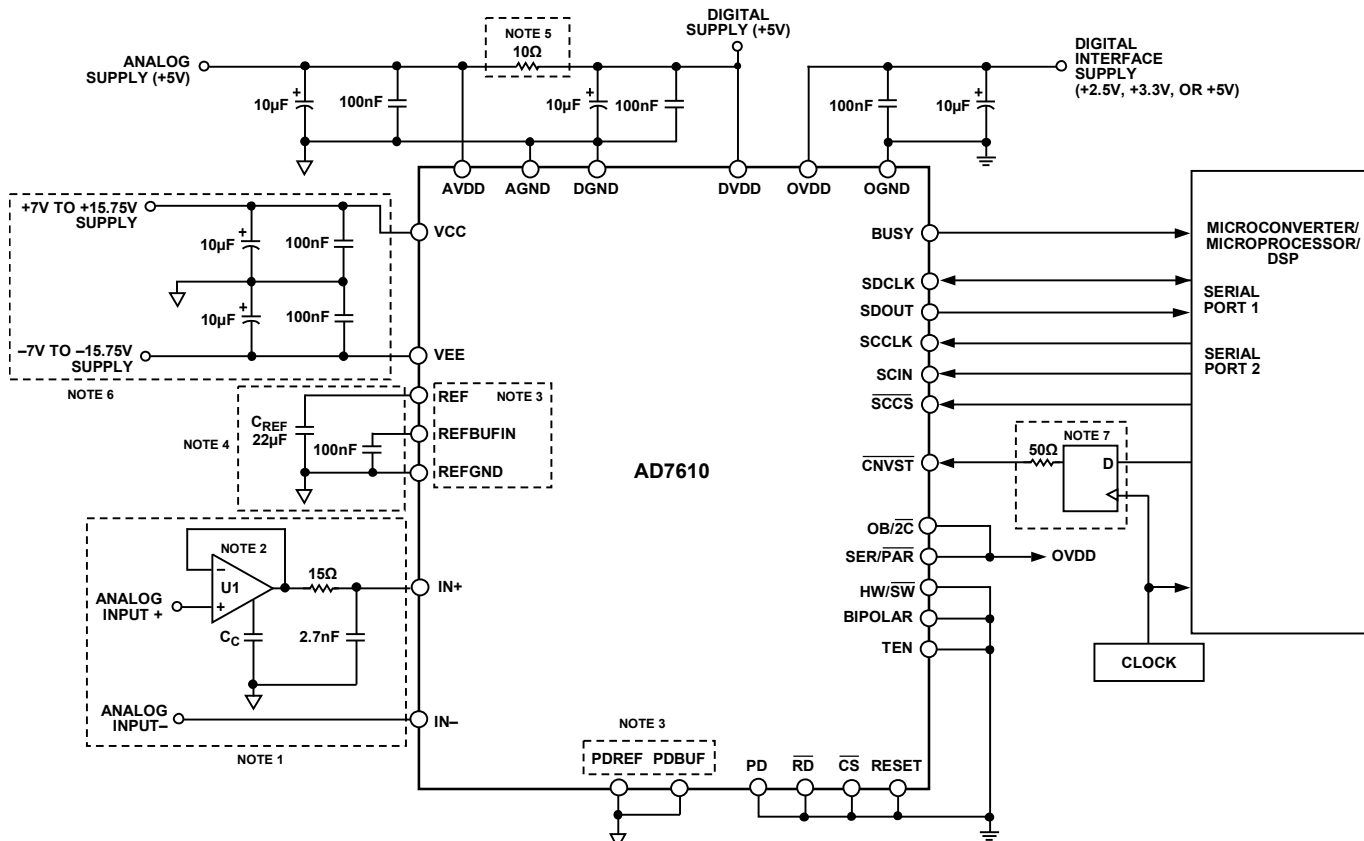
Description	$V_{\text{REF}} = 5 \text{ V}$				Digital Output Code	
	$V_{\text{IN}} = 5 \text{ V}$	$V_{\text{IN}} = 10 \text{ V}$	$V_{\text{IN}} = \pm 5 \text{ V}$	$V_{\text{IN}} = \pm 10 \text{ V}$	Straight Binary	Twos Complement
FSR – 1 LSB	4.999924 V	9.999847 V	+4.999847 V	+9.999695 V	0xFFFF ¹	0x7FFF ¹
FSR – 2 LSB	4.999847 V	9.999695 V	+4.999695 V	+9.999390 V	0xFFFE	0x7FFE
Midscale + 1 LSB	2.500076 V	5.000153 V	+152.6 μV	+305.2 μV	0x8001	0x0001
Midscale	2.5 V	5.000000 V	0 V	0 V	0x8000	0x0000
Midscale – 1 LSB	2.499924 V	4.999847 V	–152.6 μV	–305.2 μV	0x7FFF	0xFFFF
–FSR + 1 LSB	76.3 μV	152.6 μV	–4.999847 V	–9.999695 V	0x0001	0x8001
–FSR	0 V	0 V	–5 V	–10 V	0x0000 ²	0x8000 ²

¹ This is also the code for overrange analog input ($V_{\text{IN}+} - V_{\text{IN}-}$ above $V_{\text{REF}} - V_{\text{REFGND}}$).

² This is also the code for overrange analog input ($V_{\text{IN}+} - V_{\text{IN}-}$ below $V_{\text{REF}} - V_{\text{REFGND}}$).

TYPICAL CONNECTION DIAGRAM

Figure 27 shows a typical connection diagram for the AD7610 using the internal reference, serial data and serial configuration interfaces. Different circuitry from that shown in Figure 27 is optional and is discussed in the following sections.



NOTES

1. SEE ANALOG INPUT SECTION. ANALOG INPUT(-) IS REFERENCED TO AGND $\pm 0.1V$.
2. THE AD8021 IS RECOMMENDED. SEE DRIVER AMPLIFIER CHOICE SECTION.
3. THE CONFIGURATION SHOWN IS USING THE INTERNAL REFERENCE. SEE VOLTAGE REFERENCE INPUT SECTION.
4. A 22 μF CERAMIC CAPACITOR (X5R, 1206 SIZE) IS RECOMMENDED (FOR EXAMPLE, PANASONIC ECJ4YB1A226M). SEE VOLTAGE REFERENCE INPUT SECTION.
5. OPTION, SEE POWER SUPPLY SECTION.
6. THE VCC AND VEE SUPPLIES SHOULD BE VCC = [VIN(MAX) + 2V] and VEE = [VIN(MIN) - 2V] FOR BIPOLAR INPUT RANGES. FOR UNIPOLAR INPUT RANGES, VEE CAN BE 0V. SEE POWER SUPPLY SECTION.
7. OPTIONAL LOW JITTER CNVST, SEE CONVERSION CONTROL SECTION.

Figure 27. Typical Connection Diagram Shown with Serial Interface and Serial Programmable Port

06395-027

ANALOG INPUTS

Input Range Selection

In parallel mode and serial hardware mode, the input range is selected by using the BIPOLAR (bipolar) and TEN (10 Volt range) inputs. See Table 6 for pin details and the Hardware Configuration section and Software Configuration section for programming the mode selection with either pins or configuration register. Note that when using the configuration register, the BIPOLAR and TEN inputs are don't cares and should be tied to either high or low.

Input Structure

Figure 28 shows an equivalent circuit for the input structure of the AD7610.

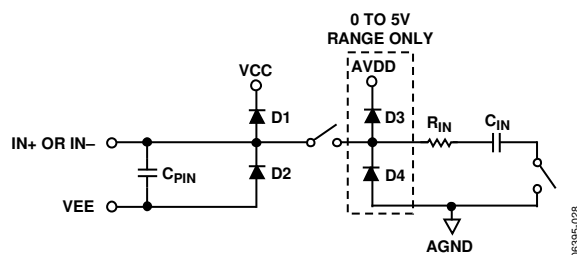


Figure 28. AD7610 Simplified Analog Input

The four diodes, D1 to D4, provide ESD protection for the analog inputs, IN+ and IN-. Care must be taken to ensure that the analog input signal never exceeds the supply rails by more than 0.3 V, because this causes the diodes to become forward-biased and to start conducting current. These diodes can handle a forward-biased current of 120 mA maximum. For instance, these conditions could eventually occur when the input buffer's U1 supplies are different from AVDD, VCC, and VEE. In such a case, an input buffer with a short-circuit current limitation can be used to protect the part although most op amps' short circuit current is <100 mA. Note that D3 and D4 are only used in the 0 V to 5 V range to allow for additional protection in applications that are switching from the higher voltage ranges.

This analog input structure allows the sampling of the differential signal between IN+ and IN-. By using this differential input, small signals common to both inputs are rejected as shown in Figure 29, which represents the typical CMRR over frequency.

For instance, by using IN- to sense a remote signal ground, ground potential differences between the sensor and the local ADC ground are eliminated.

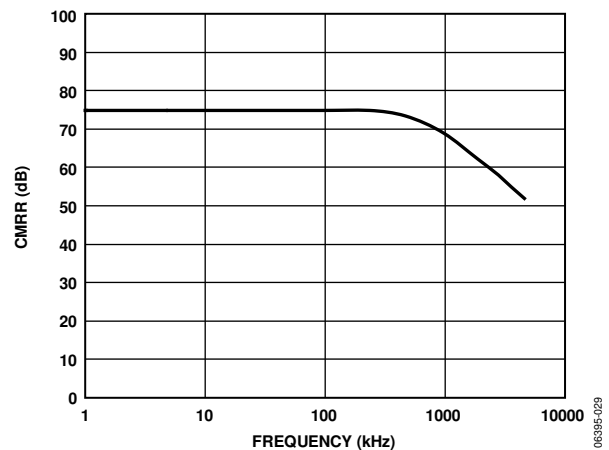


Figure 29. Analog Input CMRR vs. Frequency

During the acquisition phase for ac signals, the impedance of the analog inputs, IN+ and IN-, can be modeled as a parallel combination of Capacitor C_{PIN} and the network formed by the series connection of R_{IN} and C_{IN} . C_{PIN} is primarily the pin capacitance. R_{IN} is typically 5 k Ω and is a lumped component comprised of serial resistors and the on resistance of the switches. C_{IN} is primarily the ADC sampling capacitor and depending on the input range selected is typically 48 pF in the 0 V to 5 V range, typically 24 pF in the 0 V to 10 V and ± 5 V ranges and typically 12 pF in the ± 10 V range. During the conversion phase, when the switches are opened, the input impedance is limited to C_{PIN} .

Since the input impedance of the AD7610 is very high, it can be directly driven by a low impedance source without gain error. To further improve the noise filtering achieved by the AD7610 analog input circuit, an external, one-pole RC filter between the amplifier's outputs and the ADC analog inputs can be used, as shown in Figure 27. However, large source impedances significantly affect the ac performance, especially total harmonic distortion (THD). The maximum source impedance depends on the amount of THD that can be tolerated. The THD degrades as a function of the source impedance and the maximum input frequency.

DRIVER AMPLIFIER CHOICE

Although the AD7610 is easy to drive, the driver amplifier must meet the following requirements:

- For multichannel, multiplexed applications, the driver amplifier and the AD7610 analog input circuit must be able to settle for a full-scale step of the capacitor array at a 16-bit level (0.0015%). For the amplifier, settling at 0.1% to 0.01% is more commonly specified. This differs significantly from the settling time at a 16-bit level and should be verified prior to driver selection. The AD8021 op amp combines ultra-low noise and high gain bandwidth and meets this settling time requirement even when used with gains of up to 13.
- The noise generated by the driver amplifier needs to be kept as low as possible to preserve the SNR and transition noise performance of the AD7610. The noise coming from the driver is filtered by the external 1-pole low-pass filter as shown in Figure 27. The SNR degradation due to the amplifier is

$$SNR_{LOSS} = 20 \log \left(\frac{V_{NADC}}{\sqrt{V_{NADC}^2 + \frac{\pi}{2} f_{-3dB} (Ne_N)^2}} \right)$$

where:

V_{NADC} is the noise of the ADC, which is:

$$V_{NADC} = \frac{\frac{V_{INp-p}}{2\sqrt{2}}}{10^{\frac{SNR}{20}}}$$

f_{-3dB} is the cutoff frequency of the input filter (3.9 MHz).

N is the noise factor of the amplifier (+1 in buffer configuration).

e_N is the equivalent input voltage noise density of the op amp, in nV/ $\sqrt{\text{Hz}}$.

- The driver needs to have a THD performance suitable to that of the AD7610. Figure 15 shows the THD vs. frequency that the driver should exceed.

The AD8021 meets these requirements and is appropriate for almost all applications. The AD8021 needs a 10 pF external compensation capacitor that should have good linearity as an NPO ceramic or mica type. Moreover, the use of a noninverting +1 gain arrangement is recommended and helps to obtain the best signal-to-noise ratio.

The AD8022 can also be used when a dual version is needed and a gain of 1 is present. The AD829 is an alternative in applications where high frequency (above 100 kHz) performance is not required. In applications with a gain of 1, an 82 pF compensation capacitor is required. The AD8610 is an option when low bias current is needed in low frequency applications.

Since the AD7610 uses a large geometry, high voltage input switch, the best linearity performance is obtained when using the amplifier at its maximum full power bandwidth. Gaining the amplifier to make use of the more dynamic range of the ADC results in increased linearity errors. For applications requiring more resolution, the use of an additional amplifier with gain should precede a unity follower driving the AD7610. See Table 8 for a list of recommended op amps.

Table 8. Recommended Driver Amplifiers

Amplifier	Typical Application
ADA4841-x	12 V supply, very low noise, low distortion, low power, low frequency
AD829	± 15 V supplies, very low noise, low frequency
AD8021	± 12 V supplies, very low noise, high frequency
AD8022	± 12 V supplies, very low noise, high frequency, dual
AD8610/AD8620	± 13 V supplies, low bias current, low frequency, single/dual

VOLTAGE REFERENCE INPUT/OUTPUT

The AD7610 allows the choice of either a very low temperature drift internal voltage reference, an external reference or an external buffered reference.

The internal reference of the AD7610 provides excellent performance and can be used in almost all applications. However, the linearity performance is guaranteed only with an external reference.

Internal Reference (REF = 5 V) (PDREF = Low, PDBUF = Low)

To use the internal reference, the PDREF and PDBUF inputs must be low. This enables the on-chip band gap reference, buffer, and TEMP sensor resulting in a 5.00 V reference on the REF pin.

The internal reference is temperature-compensated to 5.000 V ± 35 mV. The reference is trimmed to provide a typical drift of 3 ppm/ $^{\circ}$ C. This typical drift characteristic is shown in Figure 19.

External 2.5 V Reference and Internal Buffer (REF = 5 V) (PDREF = High, PDBUF = Low)

To use an external reference with the internal buffer, PDREF should be high and PDBUF should be low. This powers down the internal reference and allows the 2.5 V reference to be applied to REFBUFIN producing 5 V on the REF pin. The internal reference buffer is useful in multiconverter applications since a buffer is typically required in these applications.

External 5 V Reference (PDREF = High, PDBUF = High)

To use an external reference directly on the REF pin, PDREF and PDBUF should both be high. PDREF and PDBUF power down the internal reference and the internal reference buffer, respectively. For improved drift performance, an external reference such as the [ADR445](#) or [ADR435](#) is recommended.

Reference Decoupling

Whether using an internal or external reference, the AD7610 voltage reference input (REF) has a dynamic input impedance; therefore, it should be driven by a low impedance source with efficient decoupling between the REF and REFGND inputs. This decoupling depends on the choice of the voltage reference, but usually consists of a low ESR capacitor connected to REF and REFGND with minimum parasitic inductance. A 22 μ F (X5R, 1206 size) ceramic chip capacitor (or 47 μ F tantalum capacitor) is appropriate when using either the internal reference or the ADR445/ADR435 external reference.

The placement of the reference decoupling is also important to the performance of the AD7610. The decoupling capacitor should be mounted on the same side as the ADC right at the REF pin with a thick PCB trace. The REFGND should also connect to the reference decoupling capacitor with the shortest distance and to the analog ground plane with several vias.

For applications that use multiple AD7610 or other PulSAR devices, it is more effective to use the internal reference buffer to buffer the external 2.5 V reference voltage.

The voltage reference temperature coefficient (TC) directly impacts full scale; therefore, in applications where full-scale accuracy matters, care must be taken with the TC. For instance, a ± 15 ppm/ $^{\circ}$ C TC of the reference changes full-scale by ± 1 LSB/ $^{\circ}$ C.

Temperature Sensor

When the internal reference is enabled (PDREF = PDBUF = low), the on-chip temperature sensor output (TEMP) is enabled and can be used to measure the temperature of the AD7610. To improve the calibration accuracy over the temperature range, the output of the TEMP pin is applied to one of the inputs of the analog switch (such as [ADG779](#)), and the ADC itself is used to measure its own temperature. This configuration is shown in Figure 30.

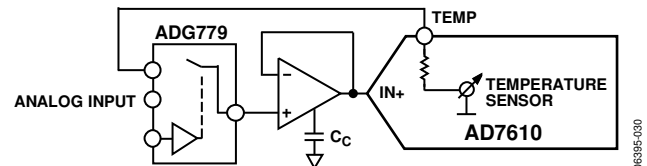


Figure 30. Use of the Temperature Sensor

POWER SUPPLIES

The AD7610 uses five sets of power supply pins:

- AVDD: analog 5 V core supply
- VCC: analog high voltage positive supply
- VEE: high voltage negative supply
- DVDD: digital 5 V core supply
- OVDD: digital input/output interface supply

Core Supplies

The AVDD and DVDD supply the AD7610 analog and digital cores respectively. Sufficient decoupling of these supplies is required consisting of at least a 10 μ F capacitor and 100 nF on each supply. The 100 nF capacitors should be placed as close as possible to the AD7610. To reduce the number of supplies needed, the DVDD can be supplied through a simple RC filter from the analog supply, as shown in Figure 27.

High Voltage Supplies

The high voltage bipolar supplies, VCC and VEE are required and must be at least 2 V larger than the maximum input, V_{IN} . For example, if using the bipolar 10 V range, the supplies should be ± 12 V minimum. Sufficient decoupling of these supplies is also required consisting of at least a 10 μ F capacitor and 100 nF on each supply. For unipolar operation, the VEE supply can be grounded with some slight THD performance degradation.

Digital Output Supply

The OVDD supplies the digital outputs and allows direct interface with any logic working between 2.3 V and 5.25 V. OVDD should be set to the same level as the system interface. Sufficient decoupling is required consisting of at least a 10 μ F capacitor and 100 nF with the 100 nF placed as close as possible to the AD7610.

Power Sequencing

The AD7610 requires sequencing of the AVDD and DVDD supplies. AVDD should come up prior to or simultaneously with DVDD. This can be achieved using the configuration in Figure 27 or sequencing the supplies in that manner. The other supplies can be sequenced as desired as long as absolute maximum ratings are observed. The AD7610 is very insensitive to power supply variations on AVDD over a wide frequency range, as shown in Figure 31.

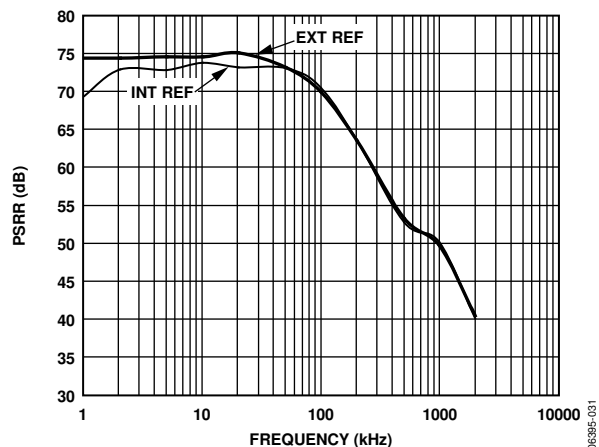


Figure 31. AVDD PSRR vs. Frequency

Power Dissipation vs. Throughput

The AD7610 automatically reduces its power consumption at the end of each conversion phase. During the acquisition phase, the operating currents are very low, which allows a significant power savings when the conversion rate is reduced (see Figure 32). This feature makes the AD7610 ideal for very low power, battery-operated applications.

It should be noted that the digital interface remains active even during the acquisition phase. To reduce the operating digital supply currents even further, drive the digital inputs close to the power rails (that is, OVDD and OGND).

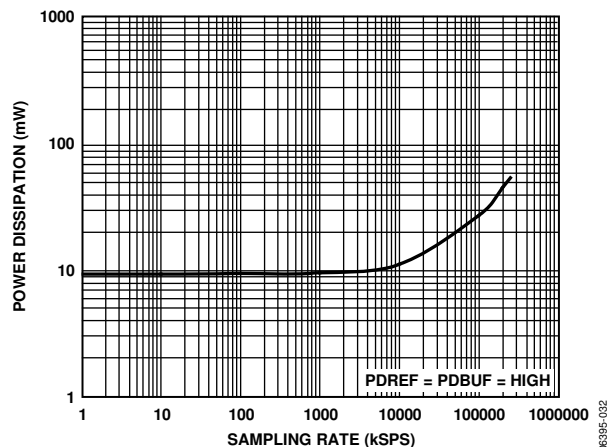


Figure 32. Power Dissipation vs. Sample Rate

Power Down

Setting PD = high powers down the AD7610, thus reducing supply currents to their minimums as shown in Figure 23. When the ADC is in power down, the current conversion (if any) is completed and the digital bus remains active. To further reduce the digital supply currents, drive the inputs to OVDD or OGND.

Power down can also be programmed with the configuration register. See the Software Configuration section for details. Note that when using the configuration register, the PD input is a don't care and should be tied to either high or low.

CONVERSION CONTROL

The AD7610 is controlled by the $\overline{\text{CNVST}}$ input. A falling edge on $\overline{\text{CNVST}}$ is all that is necessary to initiate a conversion. Detailed timing diagrams of the conversion process are shown in Figure 33. Once initiated, it cannot be restarted or aborted, even by the power-down input, PD, until the conversion is complete. The $\overline{\text{CNVST}}$ signal operates independently of $\overline{\text{CS}}$ and $\overline{\text{RD}}$ signals.

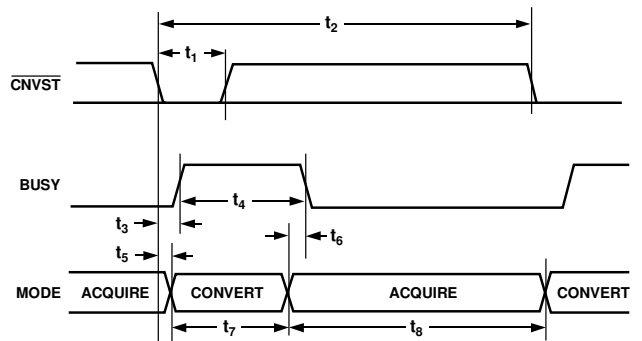


Figure 33. Basic Conversion Timing

Although $\overline{\text{CNVST}}$ is a digital signal, it should be designed with special care with fast, clean edges, and levels with minimum overshoot, undershoot, or ringing.

The $\overline{\text{CNVST}}$ trace should be shielded with ground and a low value (such as 50 Ω) serial resistor termination should be added close to the output of the component that drives this line.

For applications where SNR is critical, the $\overline{\text{CNVST}}$ signal should have very low jitter. This can be achieved by using a dedicated oscillator for $\overline{\text{CNVST}}$ generation, or by clocking $\overline{\text{CNVST}}$ with a high frequency, low jitter clock, as shown in Figure 27.

INTERFACES

DIGITAL INTERFACE

The AD7610 has a versatile digital interface that can be set up as either a serial or a parallel interface with the host system. The serial interface is multiplexed on the parallel data bus. The AD7610 digital interface also accommodates 2.5 V, 3.3 V, or 5 V logic. In most applications, the OVDD supply pin is connected to the host system interface 2.5 V to 5.25 V digital supply. Finally, by using the OB/2C input pin, both two's complement or straight binary coding can be used.

Two signals, $\overline{CS}$ and $\overline{RD}$, control the interface. When at least one of these signals is high, the interface outputs are in high impedance. Usually, $\overline{CS}$ allows the selection of each AD7610 in multicircuit applications and is held low in a single AD7610 design. $\overline{RD}$ is generally used to enable the conversion result on the data bus.

RESET

The RESET input is used to reset the AD7610. A rising edge on RESET aborts the current conversion (if any) and tristates the data bus. The falling edge of RESET resets the AD7610 and clears the data bus and configuration register. See Figure 34 for the RESET timing details.

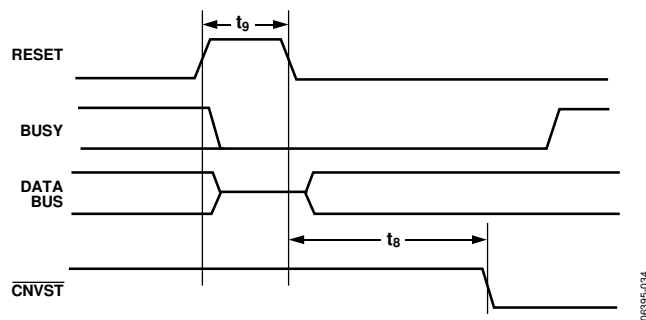


Figure 34. RESET Timing

PARALLEL INTERFACE

The AD7610 is configured to use the parallel interface when SER/PAR is held low.

Master Parallel Interface

Data can be continuously read by tying $\overline{CS}$ and $\overline{RD}$ low, thus requiring minimal microprocessor connections. However, in this mode, the data bus is always driven and cannot be used in shared bus applications (unless the device is held in RESET). Figure 35 details the timing for this mode.

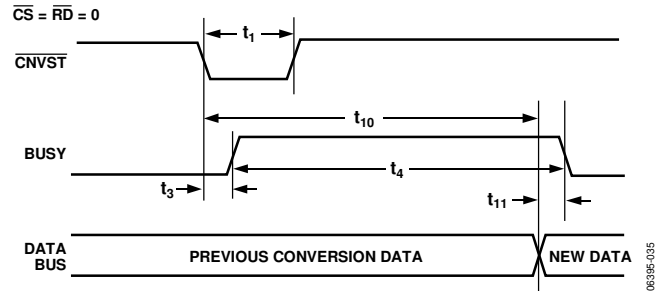


Figure 35. Master Parallel Data Timing for Reading (Continuous Read)

Slave Parallel Interface

In slave parallel reading mode, the data can be read either after each conversion, which is during the next acquisition phase, or during the following conversion, as shown in Figure 36 and Figure 37, respectively. When the data is read during the conversion, it is recommended that it is read only during the first half of the conversion phase. This avoids any potential feedthrough between voltage transients on the digital interface and the most critical analog conversion circuitry.

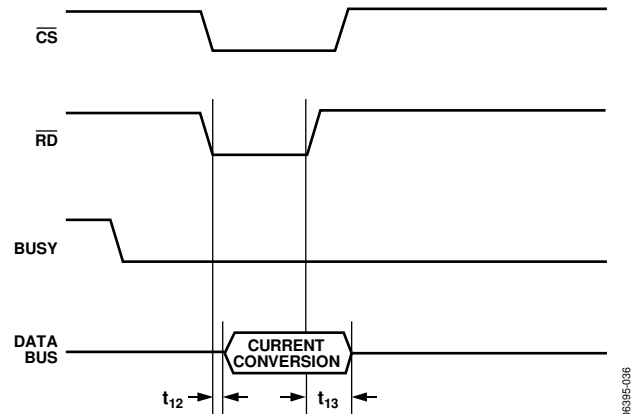


Figure 36. Slave Parallel Data Timing for Reading (Read After Convert)

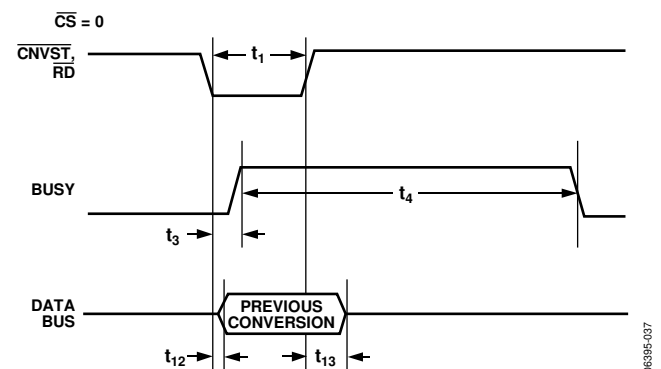


Figure 37. Slave Parallel Data Timing for Reading (Read During Convert)

8-Bit Interface (Master or Slave)

The BYTESWAP pin allows a glueless interface to an 8-bit bus. As shown in Figure 38, when BYTESWAP is low, the LSB byte is output on D[7:0] and the MSB is output on D[15:8]. When BYTESWAP is high, the LSB and MSB bytes are swapped; the LSB is output on D[15:8] and the MSB is output on D[7:0]. By connecting BYTESWAP to an address line, the 16-bit data can be read in two bytes on either D[15:8] or D[7:0]. This interface can be used in both master and slave parallel reading modes.

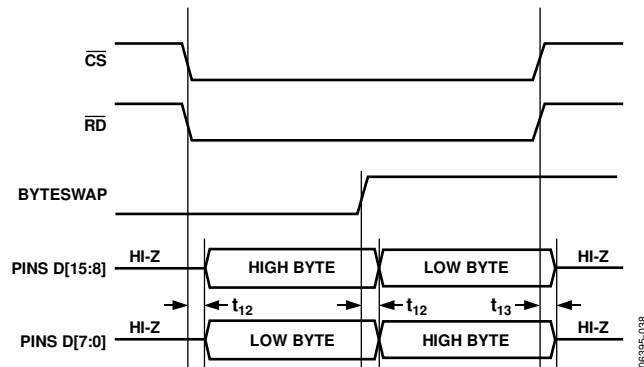


Figure 38. 8-Bit and 16-Bit Parallel Interface

SERIAL INTERFACE

The AD7610 has a serial interface (SPI-compatible) multiplexed on the data pins D[15:2]. The AD7610 is configured to use the serial interface when SER/ $\overline{\text{PAR}}$ is held high.

Data Interface

The AD7610 outputs 16 bits of data, MSB first, on the SDO_{UT} pin. This data is synchronized with the 16 clock pulses provided on the SDCLK pin. The output data is valid on both the rising and falling edge of the data clock.

Serial Configuration Interface

The AD7610 can be configured through the serial configuration register only in serial mode as the serial configuration pins are also multiplexed on the data pins D[15:12]. See the Hardware Configuration section and Software Configuration section for more information.

MASTER SERIAL INTERFACE

The pins multiplexed on D[10:2] and used for the master serial interface are: DIVSCLK[0], DIVSCLK[1], EXT/ $\overline{\text{INT}}$, INVS_{YN}C, INVSCLK, RDC, SDO_{UT}, SDCLK and SYNC.

Internal Clock (SER/ $\overline{\text{PAR}}$ = High, EXT/ $\overline{\text{INT}}$ = Low)

The AD7610 is configured to generate and provide the serial data clock, SDCLK, when the EXT/ $\overline{\text{INT}}$ pin is held low. The AD7610 also generates a SYNC signal to indicate to the host when the serial data is valid. The SDCLK, and the SYNC signals can be inverted, if desired using the INVSCLK and INVS_{YN}C inputs, respectively. Depending on the input, RDC, the data can be read during the following conversion or after each conversion. Figure 39 and Figure 40 show detailed timing diagrams of these two modes.

Read After Convert (RDC = Low, DIVSCLK[1:0] = [0 to 3])

Setting RDC = low, allows the read after conversion mode. Since the AD7610 is limited to 250kSPS and the time between conversions, $t_2 = 4\mu\text{s}$, this mode is the most recommended serial mode. Unlike the other serial modes, the BUSY signal returns low after the 16 data bits are pulsed out and not at the end of the conversion phase, resulting in a longer BUSY width (See Table 4 for BUSY timing specifications). The DIVSCLK[1:0] inputs control the SDCLK period and SDO_{UT} data rate. As a result, the maximum throughput can only be achieved in two of the DIVSCLK[1:0] settings. In this mode, the AD7610 generates a discontinuous SDCLK however, a fixed period and hosts supporting both SPI and serial ports can also be used.

Read During Convert (RDC = High)

Setting RDC = high, allows the master read (previous conversion result) during conversion mode. In this mode, the serial clock and data toggle at appropriate instances, minimizing potential feed through between digital activity and critical conversion decisions. In this mode, the SDCLK period changes since the LSBs require more time to settle and the SDCLK is derived from the SAR conversion cycle. In this mode, the AD7610 generates a discontinuous SDCLK of two different periods and the host should use an SPI interface.